VFT2080C

Vishay General Semiconductor

Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.52$ V at $I_F = 5$ A



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| PRIMARY CHARACTERISTICS | | | | |
|-------------------------|----------------|--|--|--|
| I _{F(AV)} | 2 x 10 A | | | |
| V _{RRM} | 80 V | | | |
| I _{FSM} | 100 A | | | |
| V_F at $I_F = 10$ A | 0.60 V | | | |
| T _J max. | 150 °C | | | |
| Package | ITO-220AB | | | |
| Circuit configuration | Common cathode | | | |

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | |
|--|-----------------------------------|---|------|--|--|
| PARAMETER | SYMBOL | VFT2080C | UNIT | | |
| Maximum repetitive peak reverse voltage | V _{RRM} | 80 | V | | |
| Maximum average forward rectified current per device | I _{F(AV)} | 20 | • | | |
| (fig. 1) per diode | | 10 | — A | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I _{FSM} | 100 | A | | |
| Voltage rate of change (rated V _R) | dV/dt | 10 000 | V/µs | | |
| Isolation voltage from termal to heatsink t = 1 min | V _{AC} | 1500 | V | | |
| Operating junction and storage temperature range | T _J , T _{STG} | T _J , T _{STG} -55 to +150 | | | |

| ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | | |
|---|---|---------------------------|-------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 5 A | T _A = 25 °C | V _F ⁽¹⁾ | 0.57 | - | V | |
| | I _F = 10 A | | | 0.67 | 0.81 | | |
| | I _F = 5 A | - T _A = 125 °C | | 0.52 | - | | |
| | I _F = 10 A | | | 0.60 | 0.70 | | |
| Reverse current per diode | $V_{\rm R} = 80 \text{ V} \qquad \frac{T_{\rm A} = 2}{T_{\rm A} = 1}$ | T _A = 25 °C | I _R ⁽²⁾ | 20 | 600 | μA | |
| | | T _A = 125 °C | | 10 | 20 | mA | |

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

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HALOGEN

FREE



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| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | |
|--|------------|--------------------|----------|------|
| PARAMETER | | SYMBOL | VFT2080C | UNIT |
| Typical thermal resistance | per diode | - R _{θJC} | 6.0 | °C/W |
| | per device | | 5.0 | 0/10 |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| ITO-220AB | VFT2080C-M3/4W | 1.73 | 4W | 50/tube | Tube | | |

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

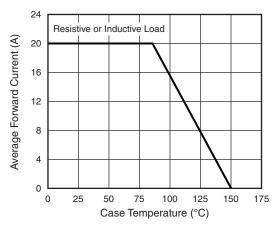


Fig. 1 - Maximum Forward Current Derating Curve

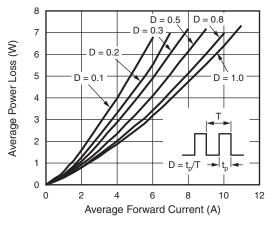


Fig. 2 - Forward Power Dissipation Characteristics

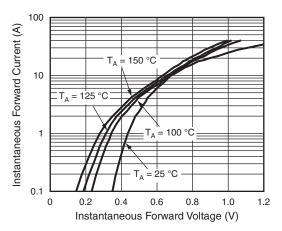


Fig. 3 - Typical Instantaneous Forward Characteristics

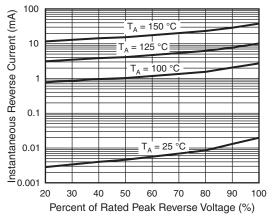
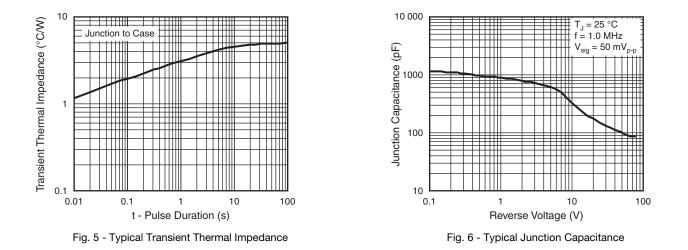


Fig. 4 - Typical Reverse Characteristics

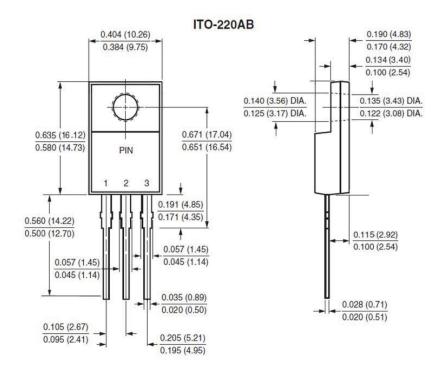
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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